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Product: Bridge Rectifiers (Power)

Bridge Rectifiers are key devices in many applications where a rectifier signal is required as Input voltage. Linear Power Supplies, SMPS, Battery Chargers, Electronic Ballast... are some applications where they are used.

Manufactured using HYPERECTIFIER© technology, we offer these devices in several different packages: SMD, Dual In Line, Round, In Line and Square Power.

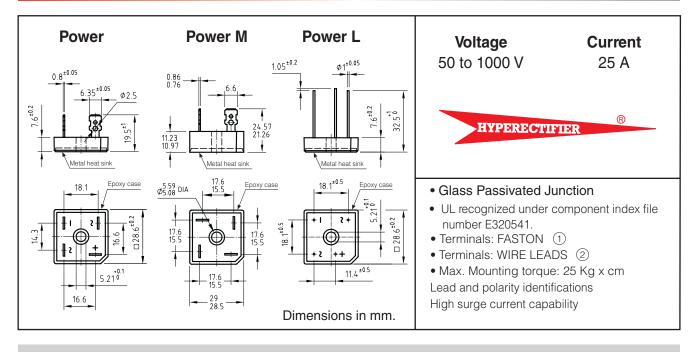
Product	Family	$I_{F(AV)}(A)$	$I_{FSM}(A)$	$V_{RRM}(V)$	$V_F(V)$	OUTLINE
FB2510L-B500/440-25L	FB25-L	25.0	300	1000	1.1	Power - Wire leads







25 Amp. Glass Pasivated Bridge Rectifiers



Maximum Ratings, according to IEC publication No. 134

	1)	FB2500	FB2501	FB2502	FB2504	FB2506	FB2508	FB2510	
	2	FB2500L	FB2501L	FB2502L	FB2504L	FB2506L	FB2508L	FB2510L	
	1	FB2500M	FB2501M	FB2502M	FB2504M	FB2506M	FB2508M	FB2510M	
V _{RRM}	Peak Recurrent Reverse Voltage (V)	50	100	200	400	600	800	1000	
V _{RMS}	Maximum RMS Voltage (V)	35	70	140	280	420	560	700	
V_R	Recommended Input Voltage (V)	20	40	80	125	250	380	500	
I _{F (AV)}	Max. Forward Current R-load: At T case = 55 °C At T case = 90 °C		25 A 17 A						
With Al Square Chassis (200 cm ² x 3 mm.) Tamb = 45 °C		10 A							
I _{FRM}	I _{FRM} Recurrent Peak Forward Current		75 A						
I _{FSM}	I _{FSM} 10 ms. Peak Forward Current		300 A						
I ² t	² t I ² t value for fusing (t = 10ms)		450 A ² sec						
Tj	T _j Operating junction temperature range		– 55 to + 150 °C						
T _{stg} Storage temperature range		– 55 to + 150 °C							

Electrical Characteristics at Tamb = 25 °C

V _F	Max. forward voltage drop per element at $I_F = 12.5 A$	1.1 V			
I _R	Maximum reverse current per element at V _{RRM} d.c.	5 μΑ			
R _{thj-C}	Typical thermal resistance junction to case	1.4 °C/W			
	Isolation voltage from case to leads	2500 Vac			